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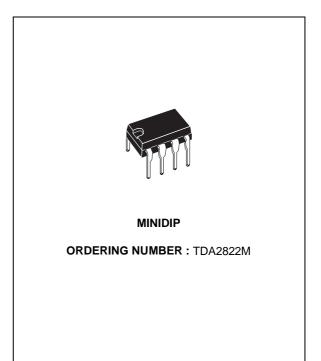


# **TDA2822M**

## DUAL LOW-VOLTAGE POWER AMPLIFIER

#### SUPPLY VOLTAGE DOWN TO 1.8V

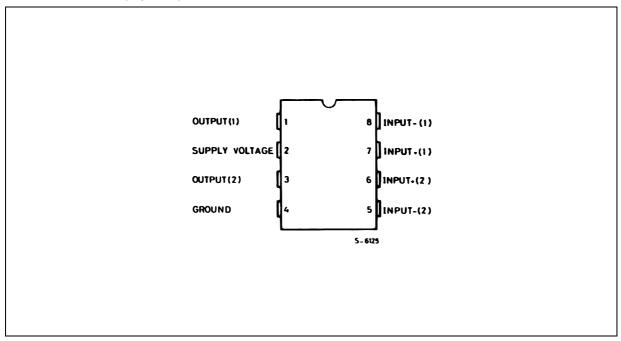
- LOW CROSSOVER DISTORSION
- LOW QUIESCENT CURRENT
- BRIDGE OR STEREO CONFIGURATION



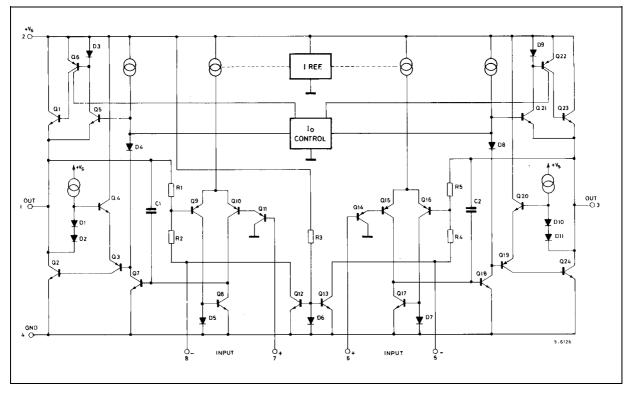
### DESCRIPTION

The TDA2822M is a monolithic integrated circuit in 8 lead Minidip package. It is intended for use as dual audio power amplifier in portable cassette players and radios.

#### PIN CONNECTION (Top view)



## SCHEMATIC DIAGRAM



## ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
Vs	Supply Voltage	15	V
lo	Peak Output Current	1	A
P <sub>tot</sub>	Total Power Dissipation at $T_{amb} = 50 \ ^{\circ}C$ at $T_{case} = 50 \ ^{\circ}C$	1 1.4	W W
T <sub>stg</sub> , T <sub>j</sub>	Storage and Junction Temperature	- 40, + 150	°C

## THERMAL DATA

Symbol	Parameter	Value	Unit
R <sub>th j-amb</sub>	Thermal Resistance Junction-ambient Max.	100	°C/W
R <sub>th j-case</sub>	Thermal Resistance Junction-pin (4) Max.	70	°C/W



Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
TEREO (	test circuit of Figure 1)		•			
Vs	Supply Voltage		1.8		15	V
Vo	Quiescent Output Voltage	$V_s = 3V$		2.7 1.2		V V
l <sub>d</sub>	Quiescent Drain Current			6	9	mA
I <sub>b</sub>	Input Bias Current			100		nA
Po	Output Power (each channel) (f = 1kHz, d = 10%)	$ \begin{array}{ll} {\sf R}_L = 32\Omega & {\sf V}_S = 9{\sf V} \\ & {\sf V}_S = 6{\sf V} \\ & {\sf V}_S = 4.5{\sf V} \\ & {\sf V}_S = 3{\sf V} \\ & {\sf V}_S = 2{\sf V} \\ {\sf R}_L = 16\Omega & {\sf V}_S = 6{\sf V} \\ {\sf R}_L = 8\Omega & {\sf V}_S = 9{\sf V} \\ & {\sf V}_S = 6{\sf V} \\ {\sf R}_L = 4\Omega & {\sf V}_S = 6{\sf V} \\ & {\sf V}_S = 4.5{\sf V} \\ & {\sf V}_S = 3{\sf V} \end{array} $	90 15 170 300 450	300 120 60 20 5 220 1000 380 650 320 110		mW
d	Distortion (f = 1kHz)	$ \begin{array}{ll} R_{L} = 32\Omega & P_{o} = 40 mW \\ R_{L} = 16\Omega & P_{o} = 75 mW \\ R_{L} = 8\Omega & P_{o} = 150 mW \end{array} $		0.2 0.2 0.2		% % %
Gv	Closed Loop Voltage Gain	f = 1kHz	36	39	41	dB
$\Delta G_{v}$	Channel Balance				± 1	dB
Ri	Input Resistance	f = 1kHz	100			kΩ
e <sub>N</sub>	Total Input Noise	$ \begin{array}{ll} R_{s} = 10 k \Omega & B = Curve \; A \\ B = 22 Hz \; to \; 22 k Hz \end{array} $		2 2.5		μV μV
SVR	Supply Voltage Rejection	f = 100Hz, C1 = C2 = 100µF	24	30		dB
Cs	Channel Separation	f = 1kHz		50		dB
RIDGE (†	est circuit of Figure 2)		•	•	•	-

## **ELECTRICAL CHARACTERISTICS** ( $V_8 = 6V$ , $T_{amb} = 25^{\circ}C$ , unless otherwise specified)

Vs	Supply Voltage		1.8		15	V
ld	Quiescent Drain Current	$R_L = \infty$		6	9	mA
V <sub>os</sub>	Output Offset Voltage (between the outputs)	$R_L = 8\Omega$			± 50	mV
I <sub>b</sub>	Input Bias Current			100		nA
Po	Output Power (f = 1kHz, d = 10%)	$ \begin{array}{ll} {\sf R}_{\sf L}=32\Omega & {\sf V}_{\sf S}=9{\sf V} \\ & {\sf V}_{\sf S}=6{\sf V} \\ & {\sf V}_{\sf S}=4.5{\sf V} \\ & {\sf V}_{\sf S}=3{\sf V} \\ & {\sf V}_{\sf S}=2{\sf V} \\ {\sf R}_{\sf L}=16\Omega & {\sf V}_{\sf S}=9{\sf V} \\ & {\sf V}_{\sf S}=6{\sf V} \\ & {\sf V}_{\sf S}=3{\sf V} \\ {\sf R}_{\sf L}=8\Omega & {\sf V}_{\sf S}=6{\sf V} \\ & {\sf V}_{\sf S}=3{\sf V} \\ {\sf R}_{\sf L}=4\Omega & {\sf V}_{\sf S}=4.5{\sf V} \\ & {\sf V}_{\sf S}=3{\sf V} \\ & {\sf V}_{\sf S}=2{\sf V} \end{array} $	320 50 900 200	1000 400 200 65 8 2000 800 120 1350 700 220 1000 350 80		mW
d	Distortion	$P_o = 0.5W$ , $R_L = 8\Omega$ , $f = 1kHz$		0.2		%
Gv	Closed Loop Voltage Gain	f = 1kHz		39		dB
Ri	Input Resistance	f = 1kHz	100			kΩ
e <sub>N</sub>	Total Input Noise	$ \begin{array}{ll} R_{s} = 10 k \Omega & B = Curve \; A \\ B = 22 Hz \; to \; 22 k Hz \end{array} $		2.5 3		μV μV
SVR	Supply Voltage Rejection	f = 100Hz		40		dB

## TDA2822M

### Figure 1 : Test Circuit (Stereo)

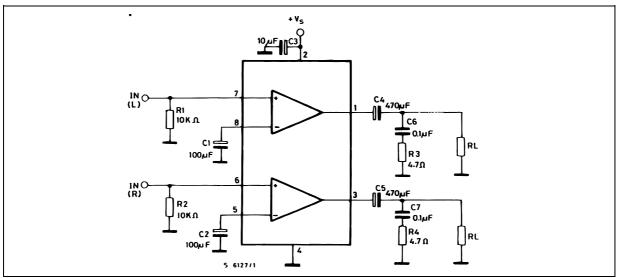


Figure 2 : Test Circuit (Bridge)

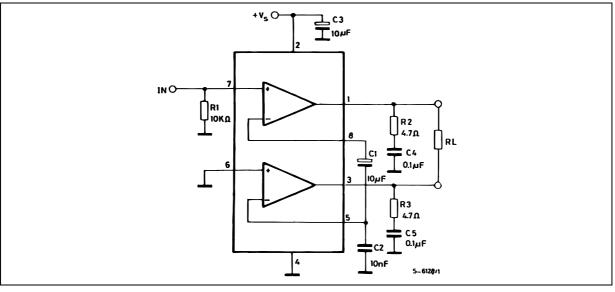
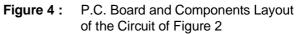
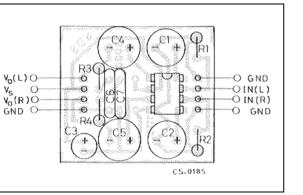
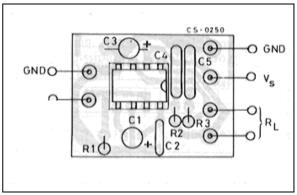


Figure 3 : P.C. Board and Components Layout of the Circuit of Figure 1

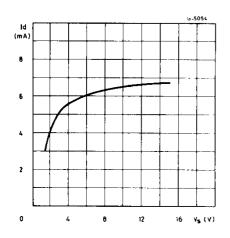






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Figure 5 : Quiescent Current versus Supply Voltage



**Figure 7 :** Output Power versus Supply Voltage (THD = 10%, f = 1kHz Stereo)

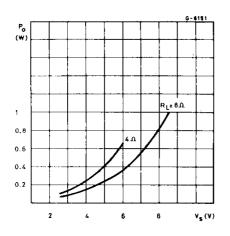
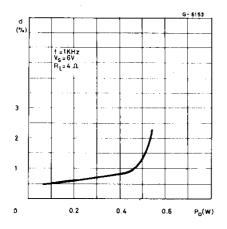


Figure 9 : Distorsion versus Output Power (Stereo)



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Figure 6 : Supply Voltage Rejection versus Frequency

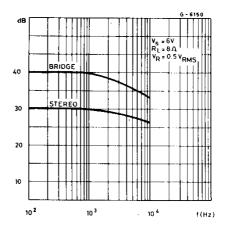


Figure 8 : Distorsion versus Output Power (Stereo)

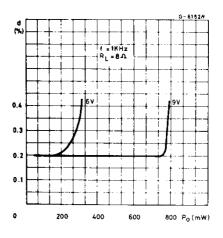
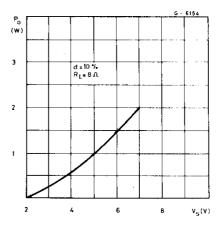


Figure 10 : Output Power versus Supply Voltage (Bridge)



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Figure 11 : Distorsion versus Output Power (Bridge)

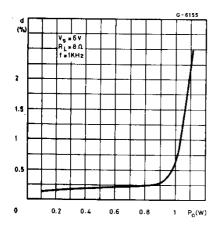


Figure 13 : Total Power Dissipation versus Output Power (Bridge)

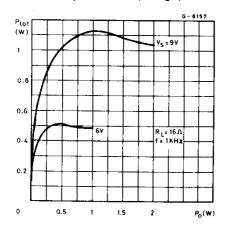


Figure 15 : Total Power Dissipation versus Output Power (Bridge)

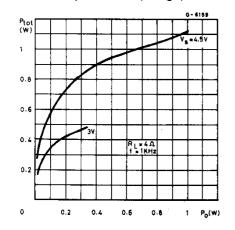


Figure 12 : Total Power Dissipation versus Output Power (Bridge)

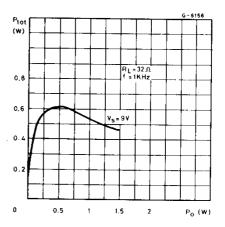
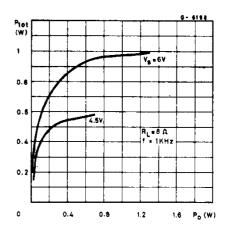


Figure 14 : Total Power Dissipation versus Output Power (Bridge)



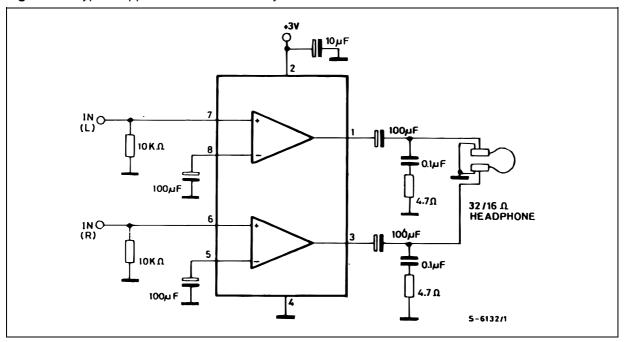
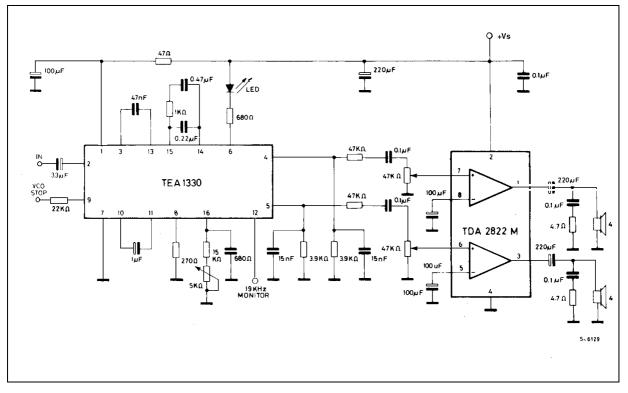


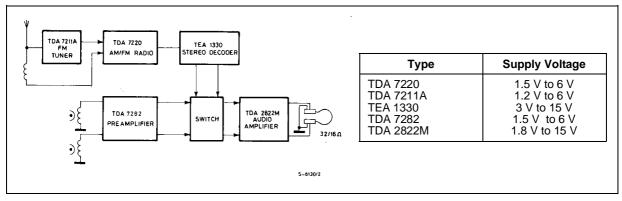
Figure 16 : Typical Application in Portable Players

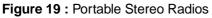


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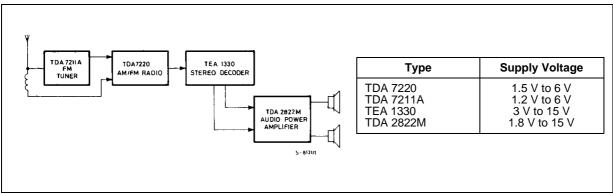
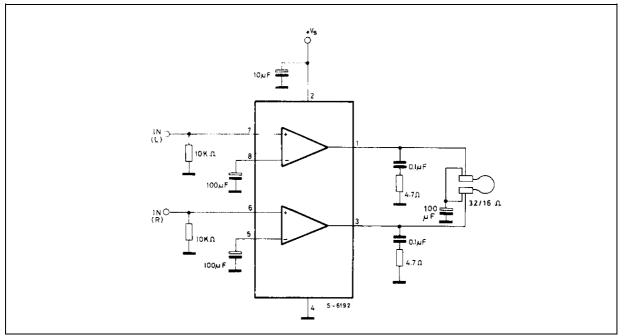
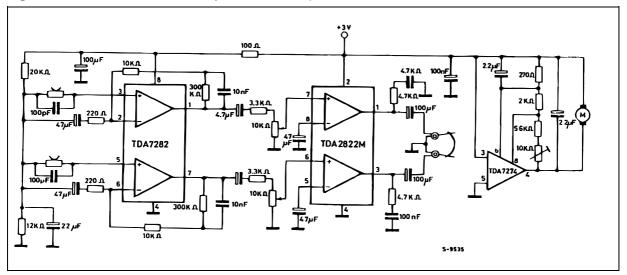


Figure 20 : Low Cost Application in Portable Players (using only one 100µF output capacitor)



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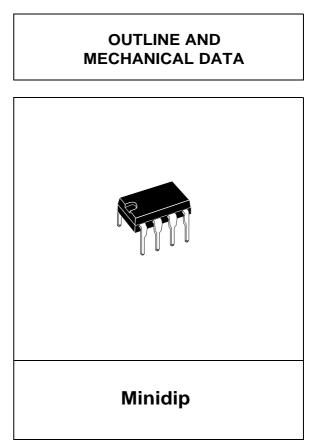


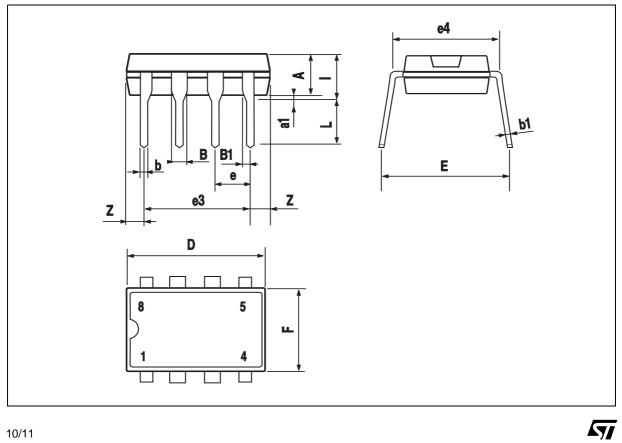




## TDA2822M

DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А		3.32			0.131		
a1	0.51			0.020			
В	1.15		1.65	0.045		0.065	
b	0.356		0.55	0.014		0.022	
b1	0.204		0.304	0.008		0.012	
D			10.92			0.430	
Е	7.95		9.75	0.313		0.384	
е		2.54			0.100		
e3		7.62			0.300		
e4		7.62			0.300		
F			6.6			0.260	
I			5.08			0.200	
L	3.18		3.81	0.125		0.150	
Z			1.52			0.060	





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